

# **NCE N-Channel Super Trench II Power MOSFET**

### **Description**

The NCEP055N60GU uses **Super Trench II** technology that is uniquely optimized to provide the most efficient high frequency switching performance. Both conduction and switching power losses are minimized due to an extremely low combination of  $R_{DS(ON)}$  and  $Q_g$ . This device is ideal for high-frequency switching and synchronous rectification.

## **Application**

- DC/DC Converter
- Ideal for high-frequency switching and synchronous rectification

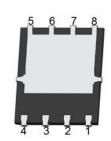
#### **General Features**

- V<sub>DS</sub> =60V,I<sub>D</sub> =75A
  - $R_{DS(ON)}$ =4.2m $\Omega$  (Typ.) @  $V_{GS}$ =10V
- Excellent gate charge x R<sub>DS(on)</sub> product(FOM)
- Very low on-resistance R<sub>DS(on)</sub>
- 150 °C operating temperature
- Pb-free lead plating

100% UIS TESTED! 100% ΔVds TESTED!

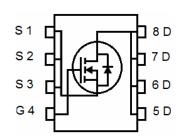
#### **DFN 5X6**





**Top View** 

**Bottom View** 



**Schematic Diagram** 

**Package Marking and Ordering Information** 

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
P055N60GU	NCEP055N60GU	DFN5X6-8L	-	-	-

## Absolute Maximum Ratings (T<sub>C</sub>=25 ℃unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	V <sub>DS</sub>	60	V
Gate-Source Voltage	V <sub>GS</sub>	±20	V
Drain Current-Continuous	I <sub>D</sub>	75	Α
Drain Current-Continuous(T <sub>C</sub> =100 °C)	I <sub>D</sub> (100℃)	55	Α
Pulsed Drain Current	I <sub>DM</sub>	300	Α
Maximum Power Dissipation	P <sub>D</sub>	70	W
Derating factor		0.56	W/℃
Single pulse avalanche energy (Note 5)	E <sub>AS</sub>	423	mJ
Operating Junction and Storage Temperature Range	$T_{J}$ , $T_{STG}$	-55 To 150	$^{\circ}$ C

#### **Thermal Characteristic**

Thermal Resistance, Junction-to-Case <sup>(Note 2)</sup>	$R_{ heta JC}$	1.8	°C/W

# NCEP055N60GU

# Electrical Characteristics (T<sub>C</sub>=25 °C unless otherwise noted)

Parameter	Symbol	Condition	Min	Тур	Max	Unit
Off Characteristics						
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	V <sub>GS</sub> =0V I <sub>D</sub> =250µA	60		-	V
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =60V,V <sub>GS</sub> =0V	-	-	1	μA
Gate-Body Leakage Current	I <sub>GSS</sub>	V <sub>GS</sub> =±20V,V <sub>DS</sub> =0V	-	-	±100	nA
On Characteristics (Note 3)						
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}$ , $I_{D}=250\mu A$	2	3	4	V
Drain-Source On-State Resistance	R <sub>DS(ON)</sub>	V <sub>GS</sub> =10V, I <sub>D</sub> =37.5A	-	4.2	5.0	mΩ
Forward Transconductance	<b>g</b> FS	V <sub>DS</sub> =5V,I <sub>D</sub> =37.5A	-	40	-	S
Dynamic Characteristics (Note4)	'		•			•
Input Capacitance	C <sub>lss</sub>	\/ 00\/\\ 0\/	-	1700	-	PF
Output Capacitance	C <sub>oss</sub>	$V_{DS}$ =30V, $V_{GS}$ =0V, F=1.0MHz	-	338	-	PF
Reverse Transfer Capacitance	C <sub>rss</sub>	F=1.UMHZ	-	18	-	PF
Switching Characteristics (Note 4)						
Turn-on Delay Time	t <sub>d(on)</sub>		-	7	-	nS
Turn-on Rise Time	t <sub>r</sub>	$V_{DD}$ =30V, $I_{D}$ =37.5A, $V_{GS}$ =10V, $R_{G}$ =3 $\Omega$	-	3	-	nS
Turn-Off Delay Time	t <sub>d(off)</sub>		-	28	-	nS
Turn-Off Fall Time	t <sub>f</sub>		-	6	-	nS
Total Gate Charge	Qg	V <sub>DS</sub> =30V,I <sub>D</sub> =37.5A,	-	28.2	-	nC
Gate-Source Charge	Q <sub>gs</sub>		-	9.1		nC
Gate-Drain Charge	$Q_{gd}$	V <sub>GS</sub> =10V	-	5.6		nC
Drain-Source Diode Characteristics			•		1	
Diode Forward Voltage (Note 3)	V <sub>SD</sub>	V <sub>GS</sub> =0V,I <sub>S</sub> =37.5A	-		1.2	V
Diode Forward Current (Note 2)	Is		-	-	75	Α
Reverse Recovery Time	t <sub>rr</sub>	T <sub>J</sub> = 25°C, I <sub>F</sub> =37.5A	-	37	-	nS
Reverse Recovery Charge	Qrr	$di/dt = 100A/\mu s^{(Note3)}$	-	47	-	nC

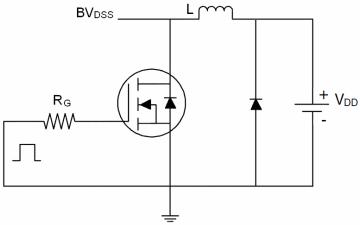
#### Notes:

- 1. Repetitive Rating: Pulse width limited by maximum junction temperature.
- 2. Surface Mounted on FR4 Board, t ≤ 10 sec.
- 3. Pulse Test: Pulse Width  $\leq$  300 $\mu$ s, Duty Cycle  $\leq$  2%.
- 4. Guaranteed by design, not subject to production
- 5. EAS condition : Tj=25  $^{\circ}\text{C}$  ,V  $_{\text{DD}}$  =30V,V  $_{\text{G}}$  =10V,L=0.5mH,Rg=25 $\Omega$

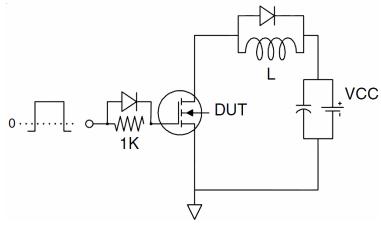


## **Test Circuit**

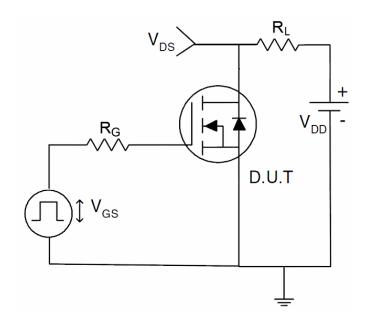
# 1) E<sub>AS</sub> test Circuit



## 2) Gate charge test Circuit

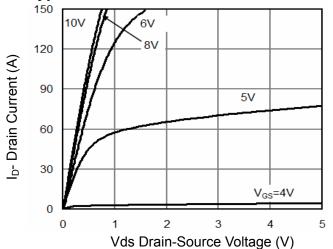


## 3) Switch Time Test Circuit

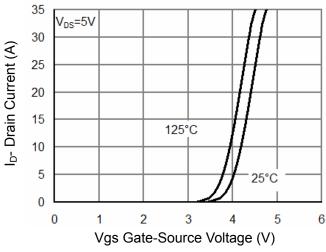




### **Typical Electrical and Thermal Characteristics**



**Figure 1 Output Characteristics** 



**Figure 2 Transfer Characteristics** 

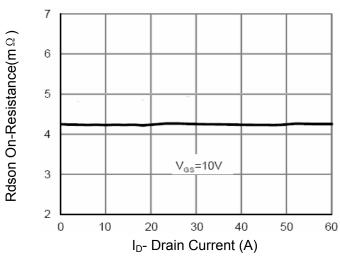
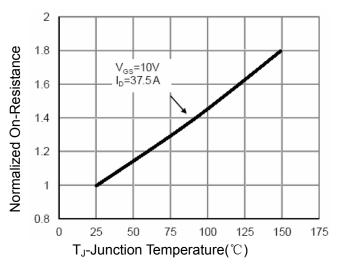


Figure 3 Rdson- Drain Current



**Figure 4 Rdson-Junction Temperature** 

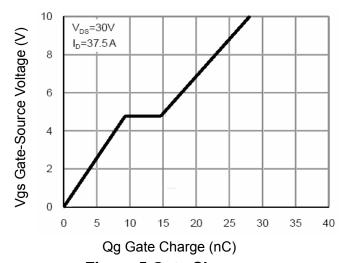


Figure 5 Gate Charge

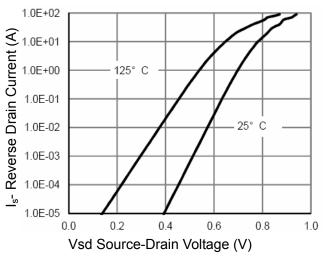


Figure 6 Source- Drain Diode Forward



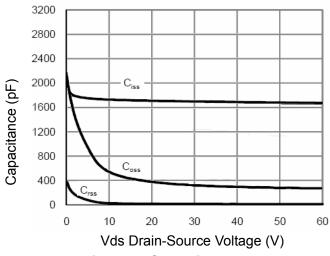


Figure 7 Capacitance vs Vds

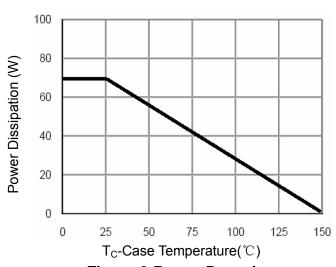
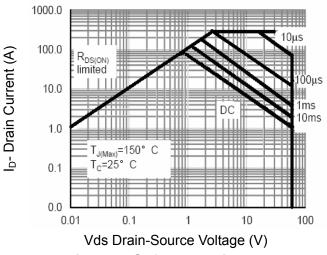


Figure 9 Power De-rating



**Figure 8 Safe Operation Area** 

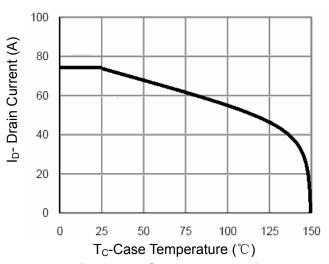
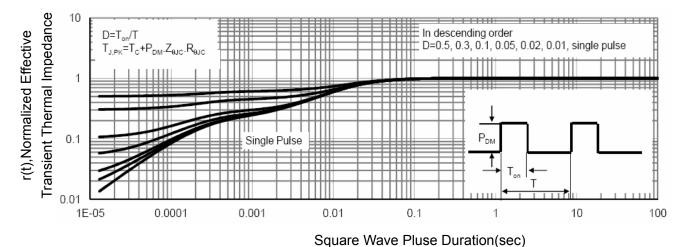


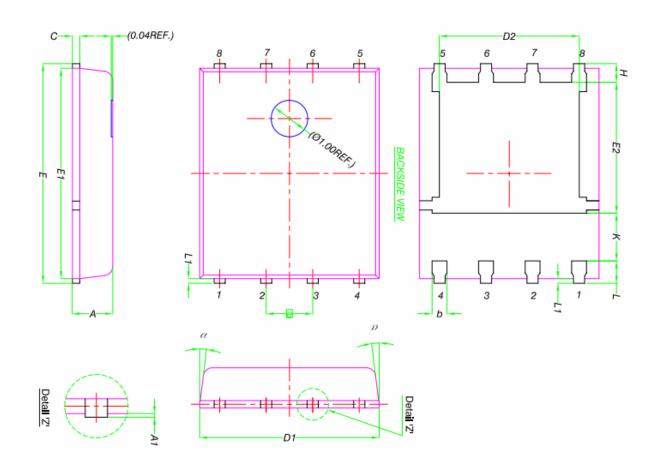
Figure 10 Current De-rating



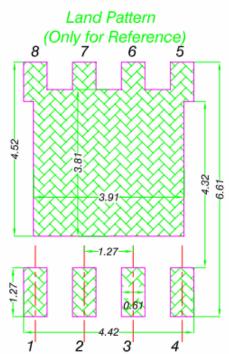
**Figure 11 Normalized Maximum Transient Thermal Impedance** 



# **DFN5X6-8L Package Information**



	MILLIMETERS				
DIM.	MIN.	NOM.	MAX.		
Α	0.90	1.00	1.10		
A1	0	-	0.05		
b	0.33	0.41	0.51		
С	0.20	0.25	0.30		
D1	4.80	4.90	5.00		
D2	3.61	3.81	3.96		
Ε	5.90	6.00	6.10		
E1	5.70	5.75	5.80		
E2	3.38	3.58	3.78		
е	1.27 BSC				
Н	H 0.41 K 1.10 L 0.51		0.61		
K			-		
L			0.71		
L1	0.06	0.13	0.20		
α	<i>0</i> °	-	12°		



#### http://www.ncepower.com

# NCEP055N60GU

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